

Over-The-Top Micropower, Rail-To-Rail Input and Output Op Amp

FEATURES

- Operates with Inputs Above V^+
- Rail-to-Rail Input and Output
- Micropower: 250μA Supply Current Max
- Gain-Bandwidth Product: 1.1MHz
- Slew Rate: 0.4V/μs
- Low Input Offset Voltage: 350μV Max
- Single Supply Input Range: -0.4V to 44V
- High Output Current: 25mA Min
- Specified on 3V, 5V and ±15V Supplies
- Output Shutdown
- Output Drives 4700pF with Output Compensation
- Reverse Battery Protection to 25V
- High Voltage Gain: 800V/mV
- High CMRR: 110dB

APPLICATIONS

- Battery or Solar Powered Systems:
 - Portable Instrumentation
 - Sensor Conditioning
- Supply Current Sensing
- Battery Monitoring
- MUX Amplifiers
- 4mA to 25mA Transmitters

DESCRIPTION

The LT[®]1637 is a rugged op amp that operates on all single and split supplies with a total voltage of 2.7V to 44V. The LT1637 has a gain-bandwidth product of 1.1MHz while drawing less than 250μA of quiescent current. The LT1637 can be shut down, making the output high impedance and reducing the quiescent current to only 3μA. The LT1637 is reverse supply protected: it draws virtually no current for reverse supply up to 25V. The input range of the LT1637 includes both supplies and the output swings to both supplies. Unlike most micropower op amps, the LT1637 can drive heavy loads; its rail-to-rail output drives 25mA. The LT1637 is unity-gain stable into all capacitive loads up to 4700pF when optional 0.22μF and 150Ω compensation is used.

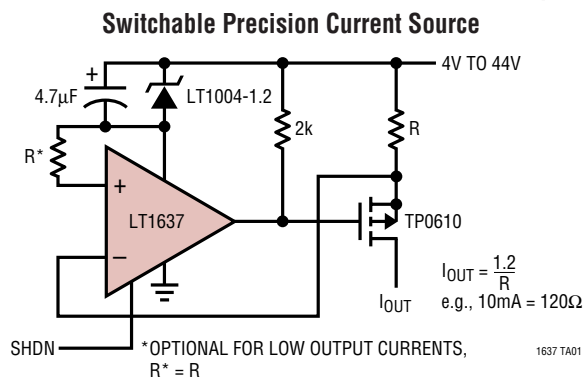
The LT1637 has a unique input stage that operates and remains high impedance when above the positive supply. The inputs take 44V both differential and common mode, even when operating on a 3V supply. Built-in resistors protect the inputs for faults below the negative supply up to 22V. There is no phase reversal of the output for inputs 5V below V_{EE} or 44V above V_{EE} , independent of V_{CC} .

The LT1637 op amp is available in the 8-pin MSOP, PDIP and SO packages.

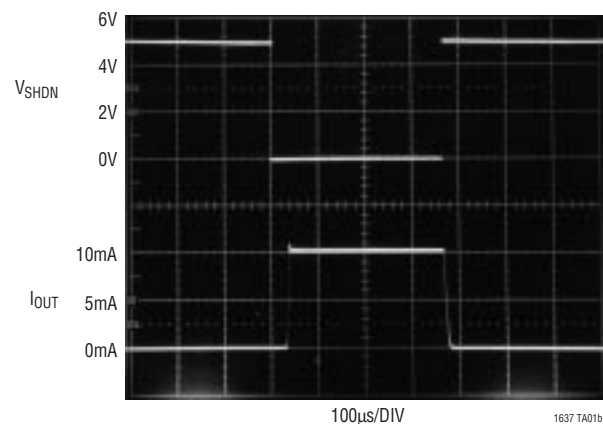
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TYPICAL APPLICATION

Over-The-Top™ Current Source with Shutdown



Current Source Timing



ABSOLUTE MAXIMUM RATINGS

(Note 1)

Total Supply Voltage (V^+ to V^-)	44V	Operating Temperature Range (Note 3) ..	-40°C to 85°C
Input Differential Voltage	44V	Specified Temperature Range (Note 4) ...	-40°C to 85°C
Input Current	$\pm 25\text{mA}$	Junction Temperature	150°C
Shutdown Pin Voltage Above V^-	32V	Storage Temperature Range	-65°C to 150°C
Shutdown Pin Current	$\pm 10\text{mA}$	Lead Temperature (Soldering, 10 sec)	300°C
Output Short-Circuit Duration (Note 2)	Continuous		

PACKAGE/ORDER INFORMATION

<p>MS8 PACKAGE 8-LEAD PLASTIC MSOP</p> <p>$T_{JMAX} = 150^{\circ}\text{C}$, $\theta_{JA} = 250^{\circ}\text{C/W}$</p>	ORDER PART NUMBER	<p>N8 PACKAGE 8-LEAD PDIP S8 PACKAGE 8-LEAD PLASTIC SO</p> <p>$T_{JMAX} = 150^{\circ}\text{C}$, $\theta_{JA} = 130^{\circ}\text{C/W}$ (N8) $T_{JMAX} = 150^{\circ}\text{C}$, $\theta_{JA} = 190^{\circ}\text{C/W}$ (S8)</p>	ORDER PART NUMBER
	LT1637CMS8		LT1637CN8 LT1637CS8 LT1637IN8 LT1637IS8
	MS8 PART MARKING		S8 PART MARKING
LTIE	1637 1637I		

Consult factory for Military grade parts.

3V AND 5V ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the specified temperature range, otherwise specifications are at $T_A = 25^{\circ}\text{C}$. $V_S = 3\text{V}$, 0V ; $V_S = 5\text{V}$, 0V ; $V_{SHDN} = V^-$, $V_{CM} = V_{OUT} = \text{Half Supply}$ unless otherwise specified. (Note 4)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage	N8, S8 Packages $0^{\circ}\text{C} \leq T_A \leq 70^{\circ}\text{C}$ $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$	●	100	350	μV
			●		550	μV
			●		700	μV
	Input Offset Voltage Drift (Note 9)	MS8 Package $0^{\circ}\text{C} \leq T_A \leq 70^{\circ}\text{C}$ $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$	●	100	350	μV
			●		750	μV
			●		900	μV
		N8, S8 Packages, $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$ MS8 Package, $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$	●	1	3	$\mu\text{V}/^{\circ}\text{C}$
			●	2	6	$\mu\text{V}/^{\circ}\text{C}$
I_{OS}	Input Offset Current	$V_{CM} = 44\text{V}$ (Note 5)	●	0.4	6.0	nA
			●		2.5	μA
I_B	Input Bias Current	$V_{CM} = 44\text{V}$ (Note 5) $V_S = 0\text{V}$	●	20	50	nA
			●	23	60	μA
			●	0.1		nA
	Input Noise Voltage	0.1Hz to 10Hz		0.6		μV_{P-P}
e_n	Input Noise Voltage Density	$f = 1\text{kHz}$		27		$\text{nV}/\sqrt{\text{Hz}}$
i_n	Input Noise Current Density	$f = 1\text{kHz}$		0.08		$\text{pA}/\sqrt{\text{Hz}}$

3V AND 5V ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the specified temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$.
 $V_S = 3\text{V}, 0\text{V}; V_S = 5\text{V}, 0\text{V}; V_{\text{SHDN}} = V^-$, $V_{\text{CM}} = V_{\text{OUT}} = \text{Half Supply}$ unless otherwise specified. (Note 4)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
R_{IN}	Input Resistance	Differential	1	2.6		$\text{M}\Omega$
		Common Mode, $V_{\text{CM}} = 0\text{V}$ to 44V	0.7	1.4		$\text{M}\Omega$
C_{IN}	Input Capacitance			4		pF
	Input Voltage Range		● 0		44	V
CMRR	Common Mode Rejection Ratio (Note 5)	$V_{\text{CM}} = 0\text{V}$ to $(V_{\text{CC}} - 1\text{V})$	● 88	110		dB
		$V_{\text{CM}} = 0\text{V}$ to 44V (Note 8)	● 80	98		dB
A_{VOL}	Large-Signal Voltage Gain	$V_S = 3\text{V}, V_O = 500\text{mV}$ to $2.5\text{V}, R_L = 10\text{k}$	● 150	400		V/mV
		$V_S = 3\text{V}, 0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$	● 100			V/mV
		$V_S = 3\text{V}, -40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$	● 75			V/mV
		$V_S = 5\text{V}, V_O = 500\text{mV}$ to $4.5\text{V}, R_L = 10\text{k}$	● 300	800		V/mV
V_{OL}	Output Voltage Swing LOW	$V_S = 5\text{V}, 0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$	● 200			V/mV
		$V_S = 5\text{V}, -40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$	● 150			V/mV
V_{OH}	Output Voltage Swing HIGH	No Load	●	3	8	mV
		$I_{\text{SINK}} = 5\text{mA}$	●	325	700	mV
		$V_S = 5\text{V}, I_{\text{SINK}} = 10\text{mA}$	●	580	1300	mV
I_{SC}	Short-Circuit Current (Note 2)	$V_S = 3\text{V}, \text{No Load}$	● 2.94	2.975		V
		$V_S = 3\text{V}, I_{\text{SOURCE}} = 5\text{mA}$	● 2.25	2.67		V
		$V_S = 5\text{V}, \text{No Load}$	● 4.94	4.975		V
		$V_S = 5\text{V}, I_{\text{SOURCE}} = 10\text{mA}$	● 3.80	4.45		V
PSRR	Power Supply Rejection Ratio	$V_S = 3\text{V}, \text{Short Output to Ground}$	10	14		mA
		$V_S = 3\text{V}, \text{Short Output to } V_{\text{CC}}$	15	45		mA
		$V_S = 5\text{V}, \text{Short Output to Ground}$	15	22		mA
		$V_S = 5\text{V}, \text{Short Output to } V_{\text{CC}}$	15	60		mA
I_{S}	Supply Current (Note 6)	$V_S = 3\text{V}$ to $12.5\text{V}, V_{\text{CM}} = V_O = 1\text{V}$	● 90	98		dB
		Minimum Supply Voltage	●		2.7	V
		Reverse Supply Voltage	●	25	40	
I_{SHDN}	Shutdown Pin Current	$I_S = -100\mu\text{A}$	●	190	250	μA
			●	295		μA
I_{SHDN}	Shutdown Pin Current	Supply Current, SHDN	●	3	12	μA
		$V_{\text{PIN5}} = 2\text{V}, \text{No Load}$ (Note 6)	●			
		$V_{\text{PIN5}} = 0.3\text{V}, \text{No Load}$ (Note 6)	●	0.2	15	nA
		$V_{\text{PIN5}} = 2\text{V}, \text{No Load}$ (Note 5)	●	1.0	5	μA
I_{SHDN}	Output Leakage Current	$V_{\text{PIN5}} = 3.3\text{V}$		2.5		μA
		$V_{\text{PIN5}} = 5\text{V}$		4.3		μA
		$V_{\text{PIN5}} = 2\text{V}, \text{No Load}$ (Note 6)	●	0.02	1	μA
I_{SHDN}	Maximum Shutdown Pin Current	$V_{\text{PIN5}} = 32\text{V}, \text{No Load}$ (Note 5)	●	20	150	μA
t_{ON}	Turn-On Time	$V_{\text{PIN5}} = 5\text{V}$ to $0\text{V}, R_L = 10\text{k}$		45		μs
t_{OFF}	Turn-Off Time	$V_{\text{PIN5}} = 0\text{V}$ to $5\text{V}, R_L = 10\text{k}$		3		μs
t_{SETTLING}	Settling Time	$0.1\% A_V = 1, \Delta V_O = 2\text{V}$		9		μs
GBW	Gain-Bandwidth Product (Note 5)	$f = 10\text{kHz}$	● 650	1000		kHz
		$0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$	● 550			kHz
		$-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$	● 500			kHz
SR	Slew Rate (Note 7)	$A_V = -1, R_L = \infty$	● 0.210	0.35		V/ μs
		$0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$	● 0.185			V/ μs
		$-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$	● 0.170			V/ μs

±15V ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the specified temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $V_S = \pm 15\text{V}$, $V_{CM} = 0\text{V}$, $V_{OUT} = 0\text{V}$, $V_{SHDN} = V^-$ unless otherwise specified. (Note 4)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage	N8, S8 Packages $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$ $-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$	●	100	450	μV
			●		650	μV
		MS8 Package $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$ $-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$	●	100	450	μV
			●		800	μV
	Input Offset Voltage Drift (Note 9)	N8, S8 Packages, $-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$ MS8 Package, $-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$	●	1	3	$\mu\text{V}/^\circ\text{C}$
			●	2	6	$\mu\text{V}/^\circ\text{C}$
I_{OS}	Input Offset Current		●	1	6	nA
I_B	Input Bias Current		●	17	50	nA
	Input Noise Voltage	0.1Hz to 10Hz		0.6		μV_{P-P}
e_n	Input Noise Voltage Density	$f = 1\text{kHz}$		27		$\text{nV}/\sqrt{\text{Hz}}$
i_n	Input Noise Current Density	$f = 1\text{kHz}$		0.08		$\text{pA}/\sqrt{\text{Hz}}$
R_{IN}	Input Resistance	Differential Common Mode, $V_{CM} = -15\text{V}$ to 14V		1	3	$\text{M}\Omega$
					2200	$\text{M}\Omega$
C_{IN}	Input Capacitance			4		pF
	Input Voltage Range		●	-15	29	V
CMRR	Common Mode Rejection Ratio	$V_{CM} = -15\text{V}$ to 29V	●	80	110	dB
A_{VOL}	Large-Signal Voltage Gain	$V_O = \pm 14\text{V}$, $R_L = 10\text{k}$ $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$ $-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$	●	100	400	V/mV
			●	75		V/mV
			●	50		V/mV
V_{OL}	Output Voltage Swing LOW	No Load $I_{SINK} = 5\text{mA}$ $I_{SINK} = 10\text{mA}$	●	-14.997	-14.95	V
			●	-14.680	-14.25	V
			●	-14.420	-13.65	V
V_{OH}	Output Voltage Swing HIGH	No Load $I_{SOURCE} = 5\text{mA}$ $I_{SOURCE} = 10\text{mA}$	●	14.9	14.967	V
			●	14.2	14.667	V
			●	13.7	14.440	V
I_{SC}	Short-Circuit Current (Note 2)	Short Output to GND $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$ $-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$	●	± 25	± 31.7	mA
			●	± 20		mA
			●	± 15		mA
PSRR	Power Supply Rejection Ratio	$V_S = \pm 1.5\text{V}$ to $\pm 22\text{V}$	●	90	115	dB
	Minimum Supply Voltage		●		± 1.35	V
I_S	Supply Current		●	230	300	μA
					370	μA
			●			
	Positive Supply Current, SHDN	$V_{PIN5} = -20\text{V}$, $V_S = \pm 22\text{V}$, No Load	●	6	40	μA
I_{SHDN}	Shutdown Pin Current	$V_{PIN5} = -21.7\text{V}$, $V_S = \pm 22\text{V}$, No Load $V_{PIN5} = -20\text{V}$, $V_S = \pm 22\text{V}$, No Load	●	0.3	15	nA
			●	0.9	8	μA
	Maximum Shutdown Pin Current	$V_{PIN5} = 32\text{V}$, $V_S = \pm 22\text{V}$	●	20	150	μA
	Output Leakage Current	$V_{PIN5} = -20\text{V}$, $V_S = \pm 22\text{V}$, No Load	●	0.02	2	μA
V_L	Shutdown Pin Input Low Voltage	$V_S = \pm 22\text{V}$	●	-21.7	-21.6	V
V_H	Shutdown Pin Input High Voltage	$V_S = \pm 22\text{V}$	●	-20.8	-20.0	V
t_{ON}	Turn-On Time	$V_{PIN5} = -10\text{V}$ to -15V , $R_L = 10\text{k}$		35		μs
t_{OFF}	Turn-Off Time	$V_{PIN5} = -15\text{V}$ to -10V , $R_L = 10\text{k}$		3		μs

±15V ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the specified temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $V_S = \pm 15\text{V}$, $V_{CM} = 0\text{V}$, $V_{OUT} = 0\text{V}$, $V_{SHDN} = V^-$ unless otherwise specified. (Note 4)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
GBW	Gain-Bandwidth Product	$f = 10\text{kHz}$	750	1100		kHz
		$0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$	● 650			kHz
		$-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$	● 600			kHz
SR	Slew Rate	$A_V = -1$, $R_L = \infty$, $V_O = \pm 10\text{V}$, Measure at $V_O = \pm 5\text{V}$		0.225	0.4	V/ μs
		$0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$	● 0.200			V/ μs
		$-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$	● 0.180			V/ μs

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2: A heat sink may be required to keep the junction temperature below absolute maximum.

Note 3: The LT1637 is guaranteed functional over the operating temperature range of -40°C to 85°C .

Note 4: The LT1637C is guaranteed to meet specified performance from 0°C to 70°C . The LT1637C is designed, characterized and expected to meet specified performance from -40°C to 85°C but is not tested or QA sampled at these temperatures. The LT1637I is guaranteed to meet specified performance from -40°C to 85°C .

Note 5: $V_S = 5\text{V}$ limits are guaranteed by correlation to $V_S = 3\text{V}$ and $V_S = \pm 15\text{V}$ or $V_S = \pm 22\text{V}$ tests.

Note 6: $V_S = 3\text{V}$ limits are guaranteed by correlation to $V_S = 5\text{V}$ and $V_S = \pm 15\text{V}$ or $V_S = \pm 22\text{V}$ tests.

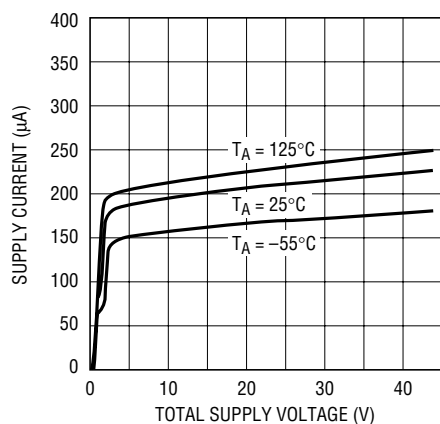
Note 7: Guaranteed by correlation to slew rate at $V_S = \pm 15\text{V}$ and GBW at $V_S = 3\text{V}$ and $V_S = \pm 15\text{V}$ tests.

Note 8: This specification implies a typical input offset voltage of $650\mu\text{V}$ at $V_{CM} = 44\text{V}$ and a maximum input offset voltage of 5.4mV at $V_{CM} = 44\text{V}$.

Note 9: This parameter is not 100% tested.

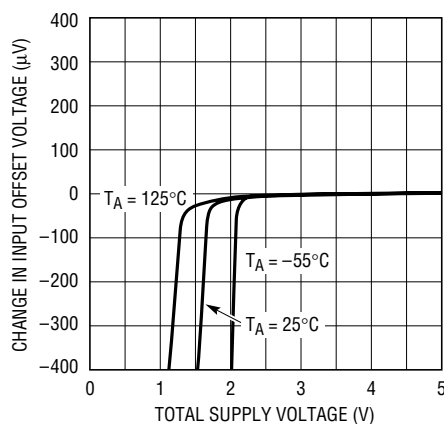
TYPICAL PERFORMANCE CHARACTERISTICS

Supply Current vs Supply Voltage



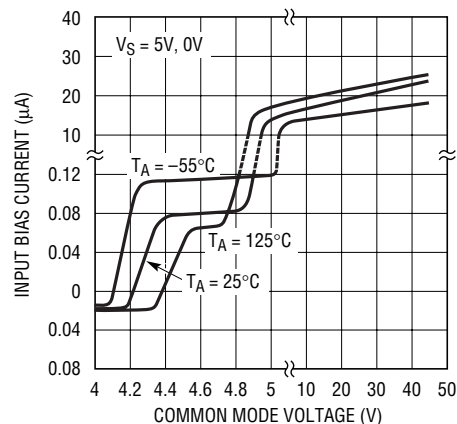
1637 G01

Minimum Supply Voltage



1637 G02

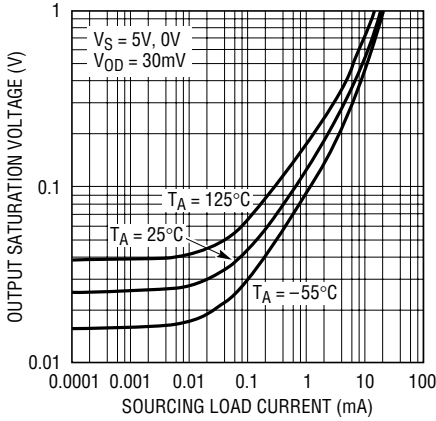
Input Bias Current vs Common Mode Voltage



1637 G03

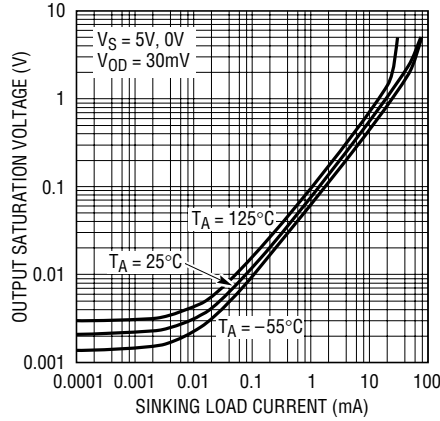
TYPICAL PERFORMANCE CHARACTERISTICS

Output Saturation Voltage vs Load Current (Output High)



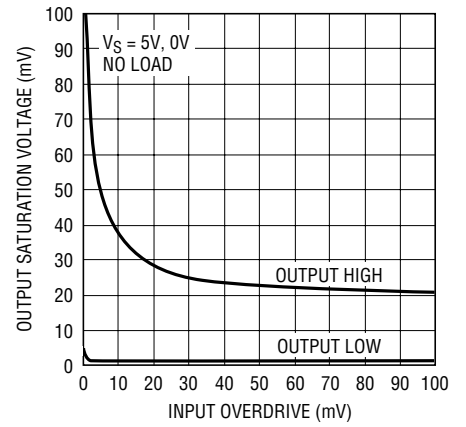
1637 G04

Output Saturation Voltage vs Load Current (Output Low)



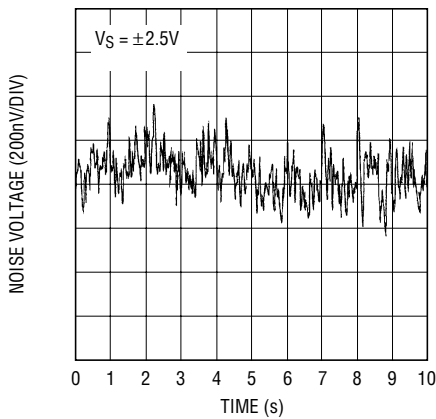
1637 G05

Output Saturation Voltage vs Input Overdrive



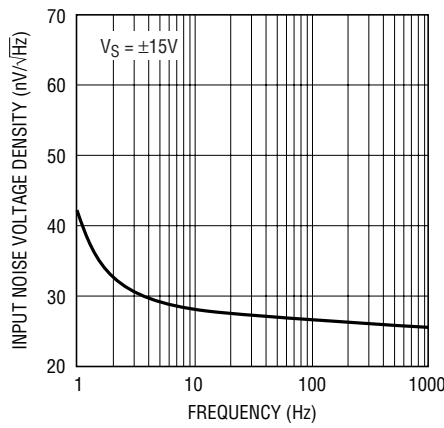
1637 G06

0.1Hz to 10Hz Noise Voltage



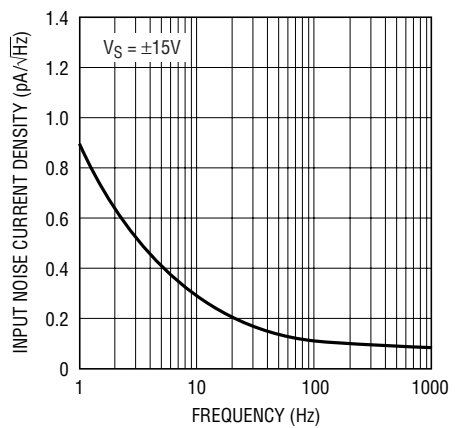
1637 G07

Noise Voltage Density vs Frequency



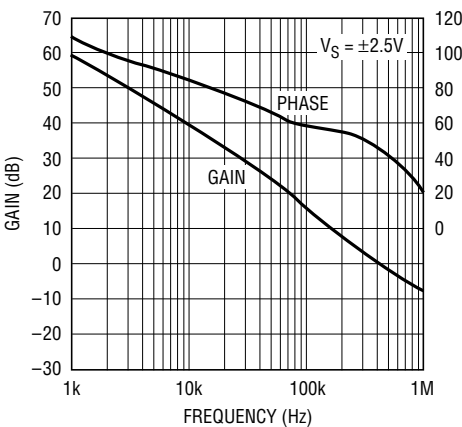
1637 G08

Input Noise Current vs Frequency



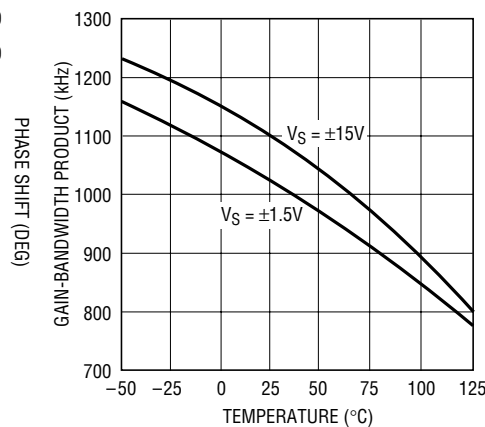
1637 G09

Open-Loop Gain and Phase Shift vs Frequency



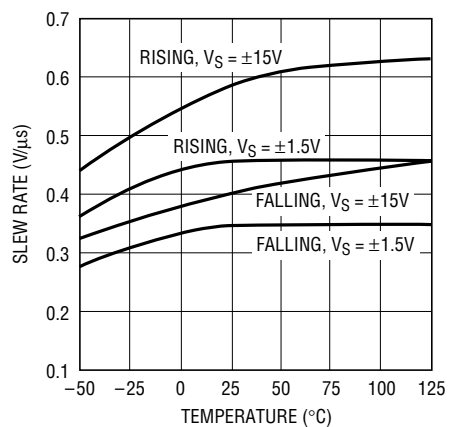
1637 G10

Gain-Bandwidth Product vs Temperature



1637 G11

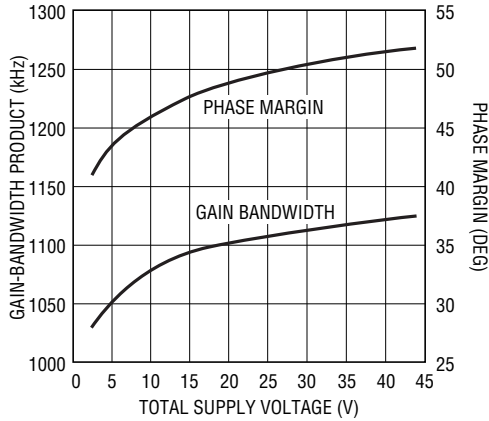
Slew Rate vs Temperature



1637 G12

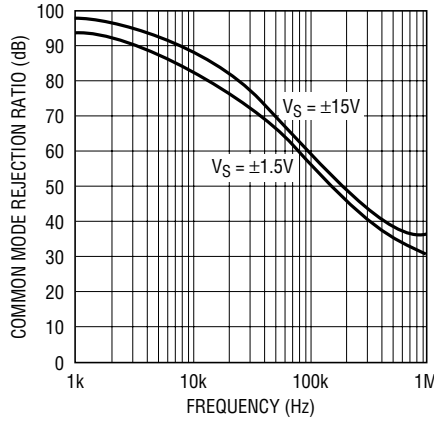
TYPICAL PERFORMANCE CHARACTERISTICS

Gain-Bandwidth Product and Phase Margin vs Supply Voltage



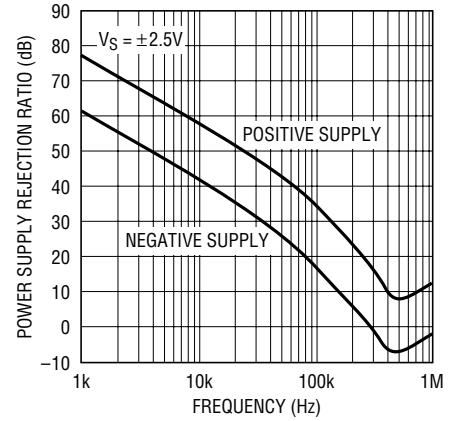
1637 G13

CMRR vs Frequency



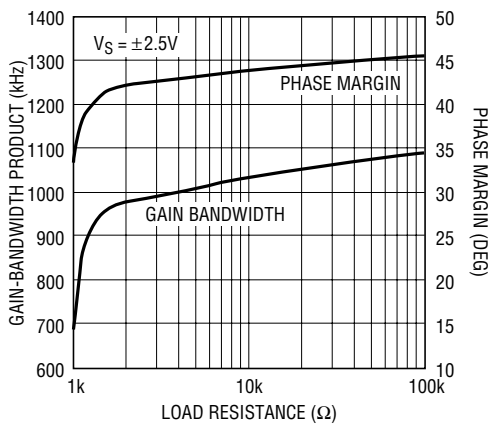
1637 G14

PSRR vs Frequency



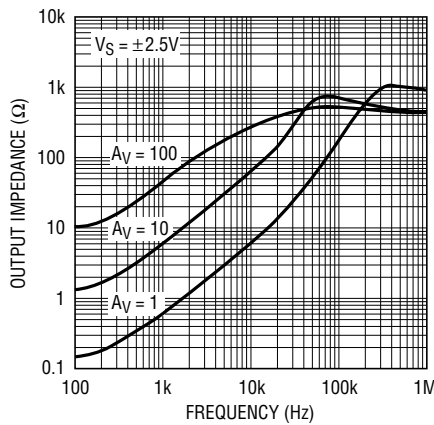
1637 G15

Gain-Bandwidth Product and Phase Margin vs Load Resistance



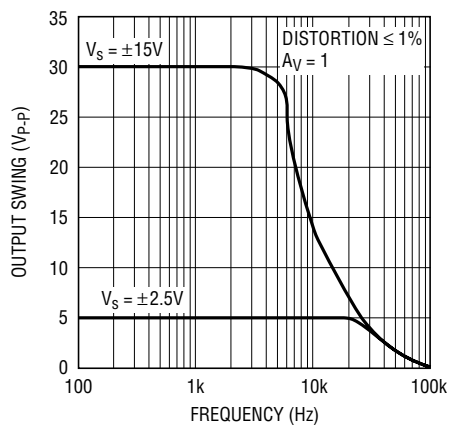
1637 G16

Output Impedance vs Frequency



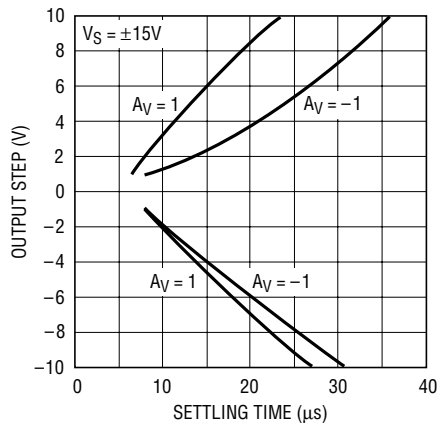
1637 G17

Undistorted Output Swing vs Frequency



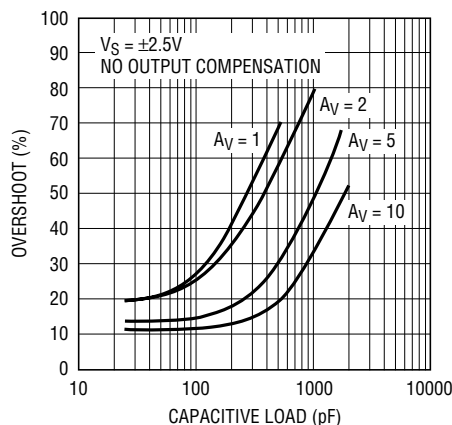
1637 G18

Settling Time to 0.1% vs Output Step



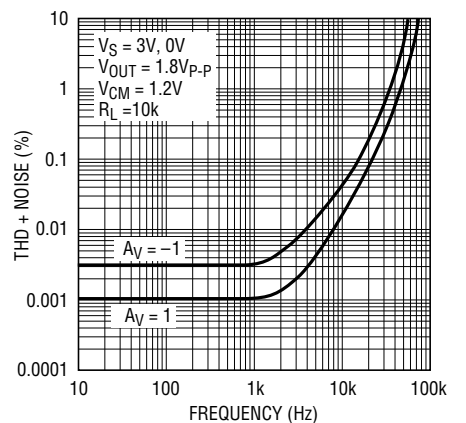
1637 G19

Capacitive Load Handling, Overshoot vs Capacitive Load



1637 G20

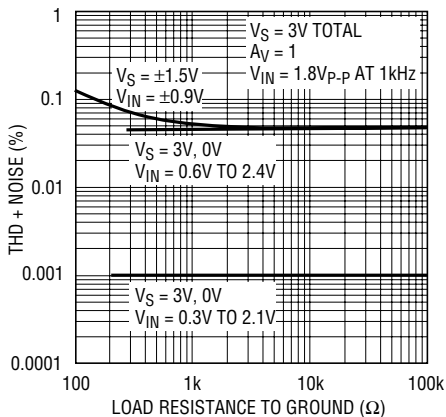
Total Harmonic Distortion + Noise vs Frequency



1637 G21

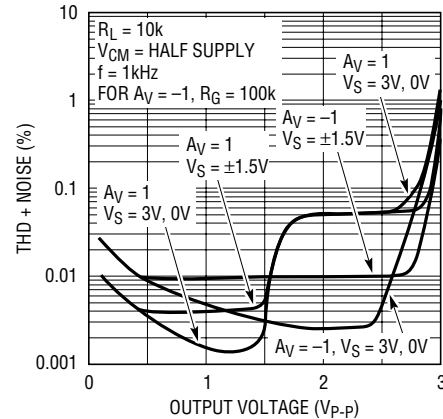
TYPICAL PERFORMANCE CHARACTERISTICS

Total Harmonic Distortion + Noise vs Load Resistance



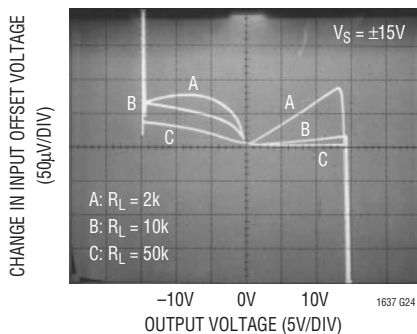
1637 G22

Total Harmonic Distortion + Noise vs Output Voltage



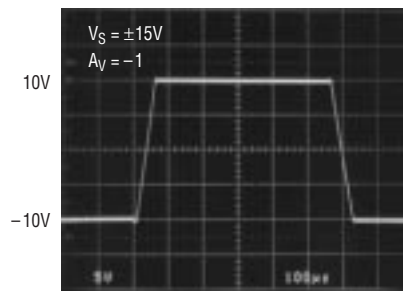
1637 G23

Open-Loop Gain



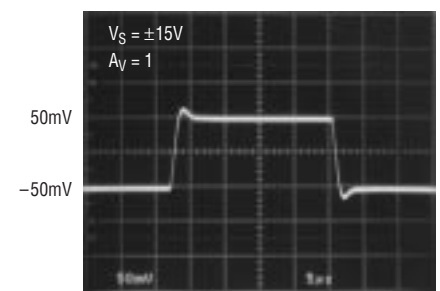
1637 G24

Large-Signal Response



1637 G25

Small-Signal Response



1637 G26

APPLICATIONS INFORMATION

Supply Voltage

The positive supply pin of the LT1637 should be bypassed with a small capacitor (about 0.01 μ F) within an inch of the pin. When driving heavy loads an additional 4.7 μ F electrolytic capacitor should be used. When using split supplies, the same is true for the negative supply pin.

The LT1637 is protected against reverse battery voltages up to 25V. In the event a reverse battery condition occurs, the supply current is typically less than 1nA.

When operating the LT1637 on total supplies of 30V or more, the supply must not be brought up faster than 1 μ s. This is especially true if low ESR bypass capacitors are used. A series RLC circuit is formed from the supply lead inductance and the bypass capacitor. 5 Ω of resistance in the supply or the bypass capacitor will dampen the tuned circuit enough to limit the rise time.

Inputs

The LT1637 has two input stages, NPN and PNP (see the Simplified Schematic), resulting in three distinct operating regions as shown in the Input Bias Current vs Common Mode typical performance curve.

For input voltages about 0.9V or more below V^+ , the PNP input stage is active and the input bias current is typically -20nA. When the input voltage is about 0.5V or less from V^+ , the NPN input stage is operating and the input bias current is typically 80nA. Increases in temperature will cause the voltage at which operation switches from the PNP stage to the NPN stage to move towards V^+ . The input offset voltage of the NPN stage is untrimmed and is typically 600 μ V.

APPLICATIONS INFORMATION

A Schottky diode in the collector of each NPN transistor of the NPN input stage allows the LT1637 to operate with either or both of its inputs above V^+ . At about 0.3V above V^+ the NPN input transistor is fully saturated and the input bias current is typically $23\mu\text{A}$ at room temperature. The input offset voltage is typically $600\mu\text{V}$ when operating above V^+ . The LT1637 will operate with its input 44V above V^- regardless of V^+ .

The inputs are protected against excursions as much as 22V below V^- by an internal 1.3k resistor in series with each input and a diode from the input to the negative supply. There is no output phase reversal for inputs up to 5V below V^- . There are no clamping diodes between the inputs and the maximum differential input voltage is 44V.

Output

The output voltage swing of the LT1637 is affected by input overdrive as shown in the typical performance curves. When monitoring input voltages within 100mV of V^+ , gain should be taken to keep the output from clipping.

The output of the LT1637 can be pulled up to 25V beyond V^+ with less than 1nA of leakage current, provided that V^+ is less than 0.5V.

The normally reverse biased substrate diode from the output to V^- will cause unlimited currents to flow when the output is forced below V^- . If the current is transient and limited to 100mA, no damage will occur.

The LT1637 is internally compensated to drive at least 200pF of capacitance under any output loading conditions. A $0.22\mu\text{F}$ capacitor in series with a 150Ω resistor between the output and ground will compensate these amplifiers for larger capacitive loads, up to 4700pF, at all output currents.

Distortion

There are two main contributors of distortion in op amps: output crossover distortion as the output transitions from sourcing to sinking current and distortion caused by nonlinear common mode rejection. Of course, if the op amp is operating inverting there is no common mode induced distortion. When the LT1637 switches between input stages there is significant nonlinearity in the CMRR.

Lower load resistance increases the output crossover distortion, but has no effect on the input stage transition distortion. For lowest distortion the LT1637 should be operated single supply, with the output always sourcing current and with the input voltage swing between ground and $(V^+ - 0.9\text{V})$. See the Typical Performance Characteristics curves.

Gain

The open-loop gain is less sensitive to load resistance when the output is sourcing current. This optimizes performance in single supply applications where the load is returned to ground. The typical performance photo of Open-Loop Gain for various loads shows the details.

Shutdown

The LT1637 can be shut down two ways: using the shutdown pin or bringing V^+ to within 0.5V of V^- . When V^+ is brought to within 0.5V of V^- both the supply current and output leakage current drop to less than 10nA. When the shutdown pin is brought 1.2V above V^- , the supply current drops to about $3\mu\text{A}$ and the output leakage current is less than $1\mu\text{A}$, independent of V^+ . In either case the input bias current is less than 0.1nA (even if the inputs are 44V above the negative supply).

The shutdown pin can be taken up to 32V above V^- . The shutdown pin can be driven below V^- , however the pin current through the substrate diode should be limited with an external resistor to less than 10mA.

Input Offset Nulling

The input offset voltage can be nulled by placing a 10k potentiometer between Pins 1 and 8 with its wiper to V^- (see Figure 1). The null range will be at least $\pm 3\text{mV}$.

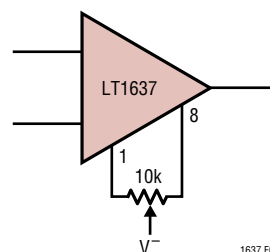
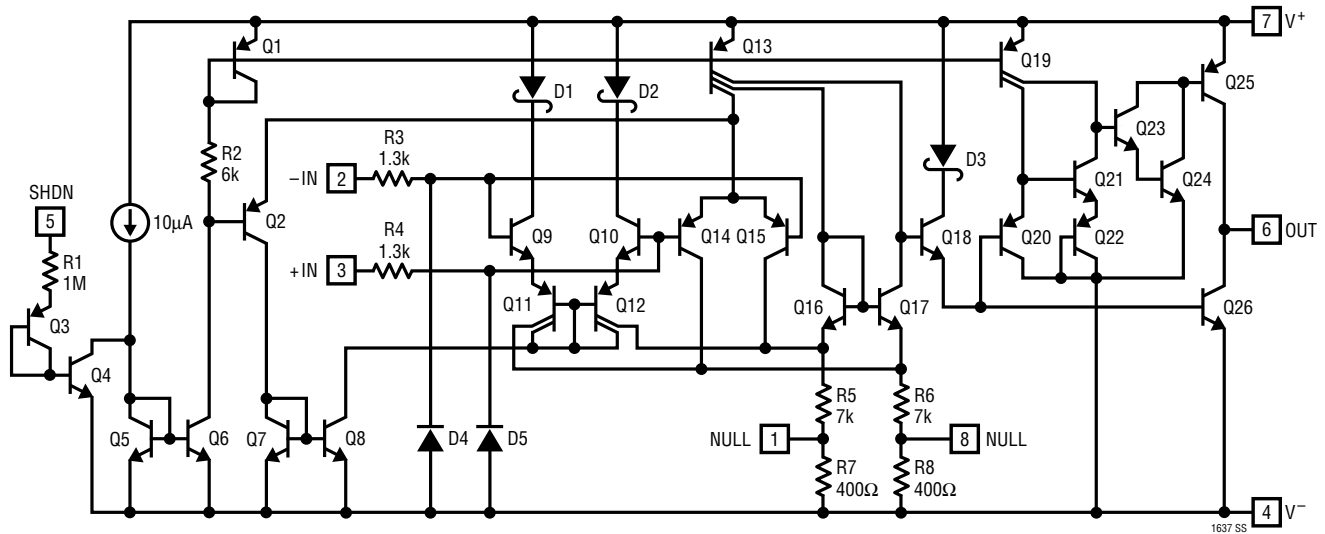


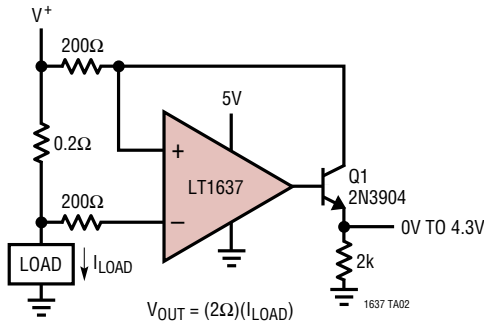
Figure 1. Input Offset Nulling

SIMPLIFIED SCHEMATIC

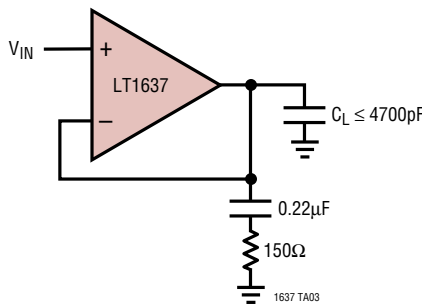


TYPICAL APPLICATIONS

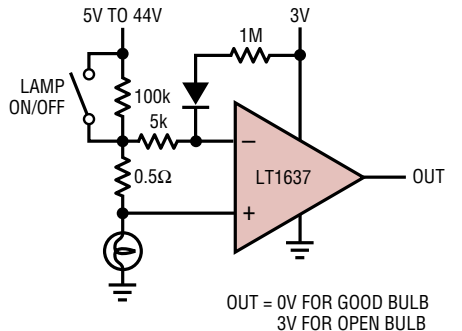
Positive Supply Rail Current Sense



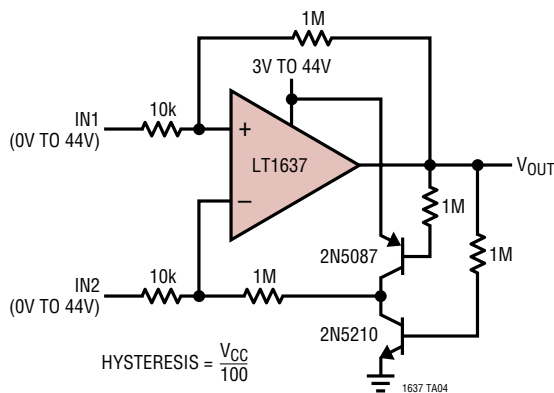
Optional Output Compensation for Capacitive Loads Greater Than 200pF



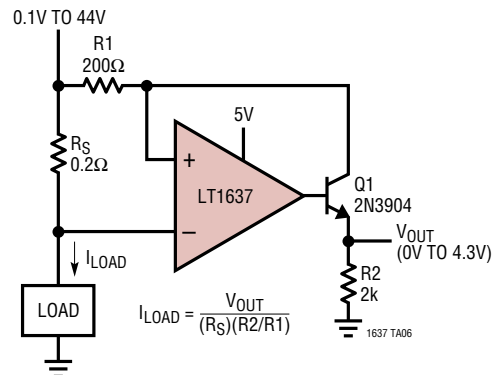
Lamp Outage Detector



Over-The-Top Comparator with Hysteresis

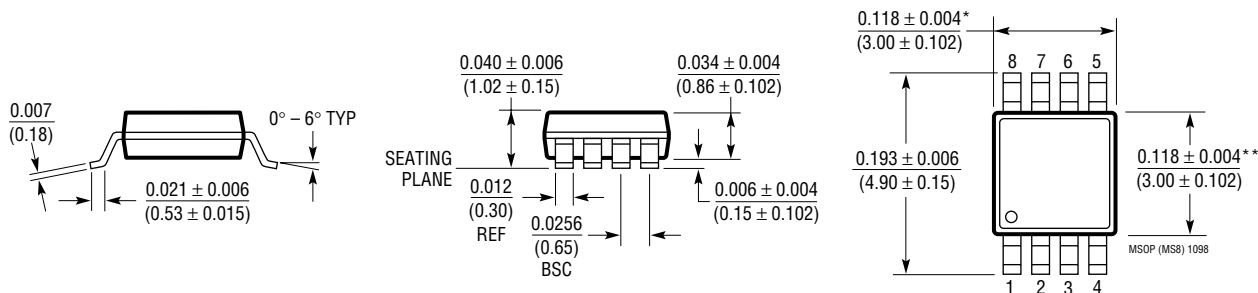


Over-The-Top Current Sense



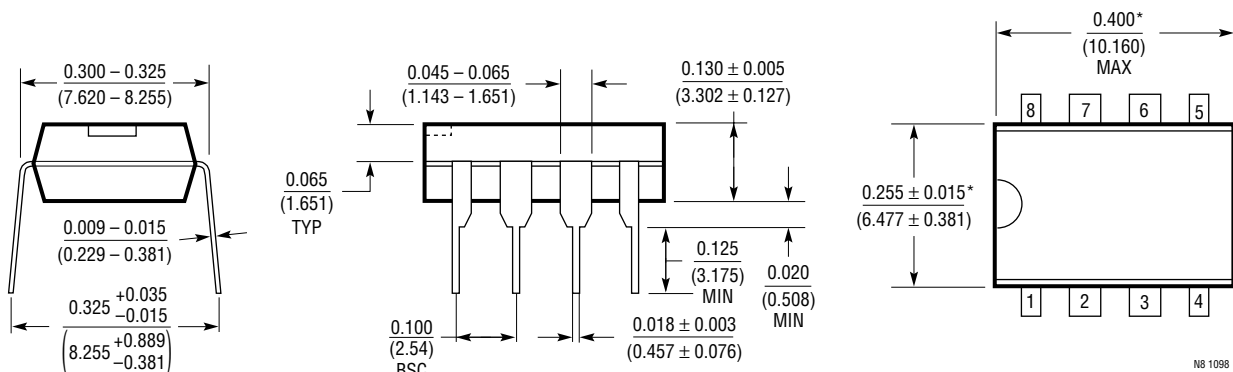
PACKAGE DESCRIPTION Dimensions in inches (millimeters) unless otherwise noted.

MS8 Package
8-Lead Plastic MSOP
 (LTC DWG # 05-08-1660)



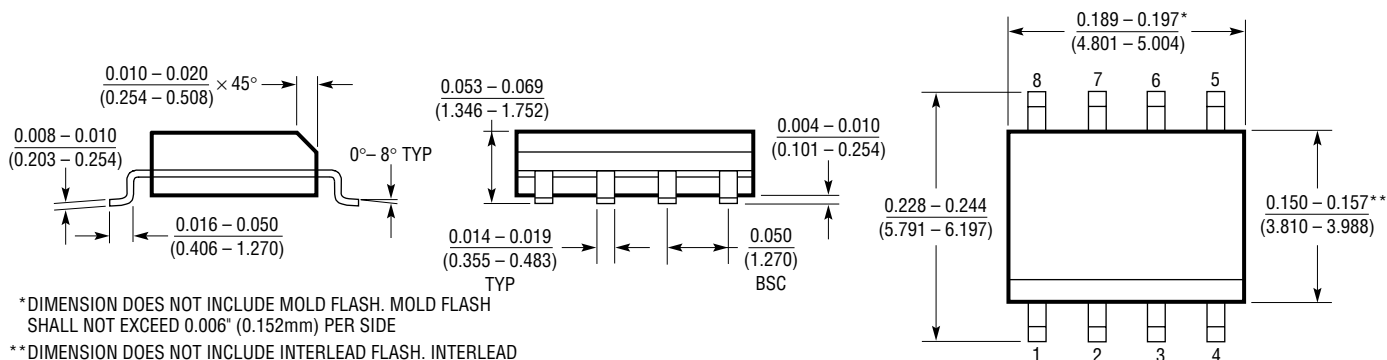
- * DIMENSION DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.006" (0.152mm) PER SIDE
- ** DIMENSION DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS. INTERLEAD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.006" (0.152mm) PER SIDE

N8 Package
8-Lead PDIP (Narrow 0.300)
 (LTC DWG # 05-08-1510)



- * THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.010 INCH (0.254mm)

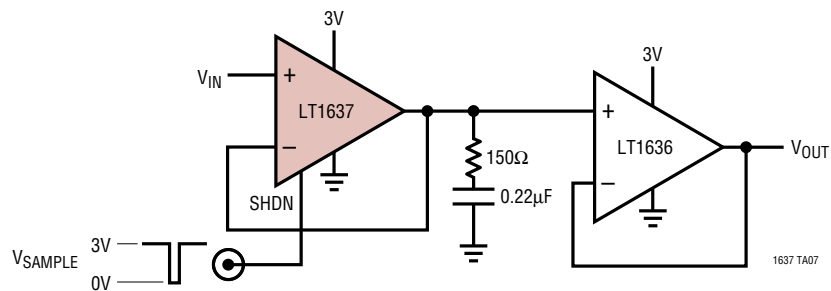
S8 Package
8-Lead Plastic Small Outline (Narrow 0.150)
 (LTC DWG # 05-08-1610)



- * DIMENSION DOES NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.006" (0.152mm) PER SIDE
- ** DIMENSION DOES NOT INCLUDE INTERLEAD FLASH. INTERLEAD FLASH SHALL NOT EXCEED 0.010" (0.254mm) PER SIDE

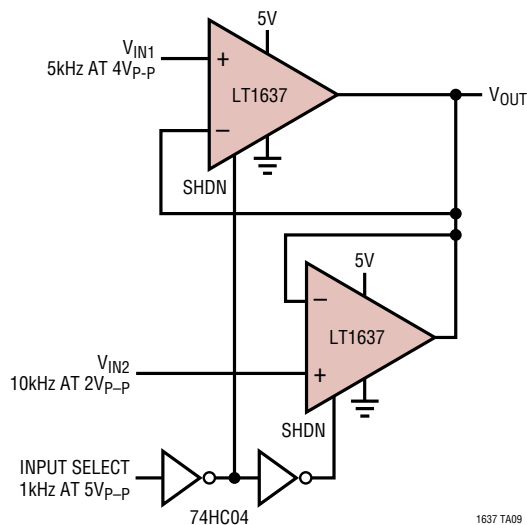
TYPICAL APPLICATIONS

Sample-and-Hold

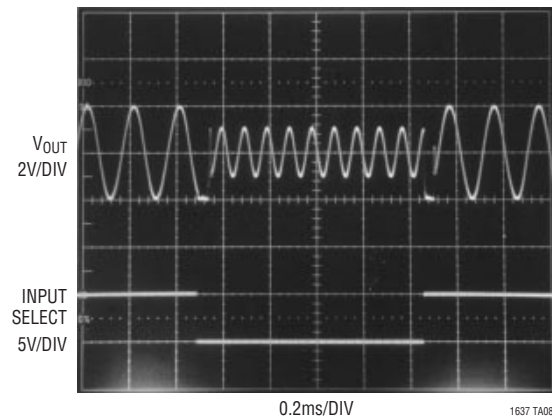


DROOP (LT1636 BUFFER): 200mV/s
 DROOP INTO HIGH IMPEDANCE: LESS THAN 0.625mV/s

MUX Amplifier



MUX Amplifier Waveforms



RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1078/LT1079 LT2078/LT2079	Dual/Quad 55μA Max, Single Supply, Precision Op Amps	Input/Output Common Mode Includes Ground, 70μV $V_{OS(MAX)}$ and 2.5μV/°C Drift (Max), 200kHz GBW, 0.07V/μs Slew Rate
LT1178/LT1179 LT2178/LT2179	Dual/Quad 17μA Max, Single Supply, Precision Op Amps	Input/Output Common Mode Includes Ground, 70μV $V_{OS(MAX)}$ and 4μV/°C Drift (Max), 85kHz GBW, 0.04V/μs Slew Rate
LT1366/LT1367	Dual/Quad Precision, Rail-to-Rail Input and Output Op Amps	475μV $V_{OS(MAX)}$, 500V/mV $A_{VOL(MIN)}$, 400kHz GBW
LT1490/LT1491	Dual/Quad Over-The-Top Micropower, Rail-to-Rail Input and Output Op Amps	Single Supply Input Range: -0.4V to 44V, Micropower 50μA per Amplifier, Rail-to-Rail Input and Output, 200kHz GBW
LT1636	Single Over-The-Top Micropower Rail-to-Rail Input and Output Op Amp	55μA Supply Current, V_{CM} Extends 44V above V_{EE} , Independent of V_{CC} ; MSOP Package, Shutdown Function
LT1638/LT1639	Dual/Quad 1.2MHz Over-The-Top Micropower, Rail-to-Rail Input and Output Op Amps	0.4V/μs Slew Rate, 230μA Supply Current per Amplifier
LT1782	Micropower, Over-The-Top, SOT-23, Rail-to-Rail Input and Output Op Amp	SOT-23, 800μV $V_{OS(MAX)}$, $I_S = 55μA$ (Max), Gain-Bandwidth = 200kHz, Shutdown Pin
LT1783	1.2MHz, Over-The-Top, Micropower, Rail-to-Rail Input and Output Op Amp	SOT-23, 800μV $V_{OS(MAX)}$, $I_S = 300μA$ (Max), Gain-Bandwidth = 1.2MHz, Shutdown Pin